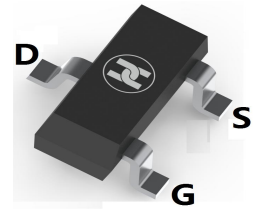


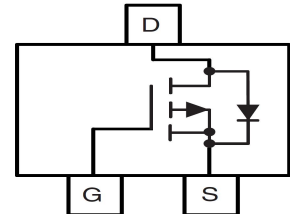
LOW VOLTAGE MOSFET (P-CHANNEL)

FEATURES

- $V_{DS}=-15V, R_{DS(ON)} \leq 110m\Omega @ V_{GS}=-4.5V, I_D=-1A$
- Low on-resistance and low gate charge
- For Load switch applications
- Surface Mount device



SOT-23



MECHANICAL DATA

- Case: SOT-23
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)

MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	-15	V
Gate-source voltage	V_{GS}	± 10	V
Continuous drain current	I_D	$T_A=25^\circ C$ -3	A
		$T_A=70^\circ C$ -2.5	A
Pulsed drain current	I_{DM}	-26	A
Power dissipation	P_D	$T_A=25^\circ C$ 1.5	W
		$T_A=70^\circ C$ 1	W
Thermal resistance from Junction to ambient	$R_{\theta JA}$	100	$^\circ C/W$
Junction temperature	T_J	150	$^\circ C$
Storage temperature	T_{STG}	-55~+150	$^\circ C$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Drain-Source breakdown voltage	$V_{(BR)DSS}^*$	-15			V	$V_{GS}=0V, I_D=-250\mu A$
Zero gate voltage drain current	I_{DSS}^*			-1	μA	$V_{DS}=-15V, V_{GS}=0V$
Gate-body leakage current	I_{GSS}^*			± 10	μA	$V_{DS}=0V, V_{GS}=\pm 10V$
Gate-threshold voltage	$V_{GS(th)}^*$	-0.3	-0.7	-1.1	V	$V_{DS}=V_{GS}, I_D=-250\mu A$
On state drain current	$I_{D(ON)}^*$	-26			A	$V_{GS}=-4.5V, V_{DS}=-5V$
Drain-source on-resistance	$R_{DS(ON)}^*$		79	110	m Ω	$V_{GS}=-4.5V, I_D=-1A$
			107	160	m Ω	$V_{GS}=-2.5V, I_D=-1A$
			151	175	m Ω	$V_{GS}=-1.8V, I_D=-1A$
			170		m Ω	$V_{GS}=-1.5V, I_D=-1A$
Forward transconductance	g_{FS}		20		S	$V_{DS}=-5V, I_D=-3A$
Gate resistance	R_g	6	12.2	20	Ω	$V_{DS}=0V, V_{GS}=0V, f=1MHz$
Input capacitance	C_{iss}	400	470	505	pF	$V_{DS}=-10V, V_{GS}=0V, f=1MHz$
Output capacitance	C_{oss}	40	53	70	pF	
Reverse transfer capacitance	C_{rss}	28	42	65	pF	$V_{GS}=-4.5V, V_{DS}=-10V, R_{GEN}=3\Omega, R_L=2.5\Omega$
Turn-on delay time	$t_{d(on)}$		13		nS	
Turn-on rise time	t_r		9		nS	
Turn-off delay time	$t_{d(off)}$		19		nS	
Turn-off fall time	t_f		9		nS	$V_{DS}=-10V, V_{GS}=-4.5V, I_D=-2A$
Total gate charge	Q_g	2.4	3.9	5.5	nC	
Gate-source charge	Q_{gs}	0.8	1	1.2	nC	
Gate-drain charge	Q_{gd}	1.3	2.0	2.8	nC	
Diode forward voltage	V_{SD}		-0.64	-1	V	$I_S=-1A, V_{GS}=0V$
Diode forward current	I_S			-2	A	
Body Diode Reverse Recovery Time	t_{rr}	20	26	32	nS	$I_F=-1A, di/dt=500A/\mu s$
Body Diode Reverse Recovery Charge	Q_{rr}	40	51	62	nC	

* Pulse test ; Pulse width $\leq 300\mu s$, Duty cycle $\leq 0.5\%$.

LOW VOLTAGE MOSFET (P-CHANNEL)

Typical Characteristics

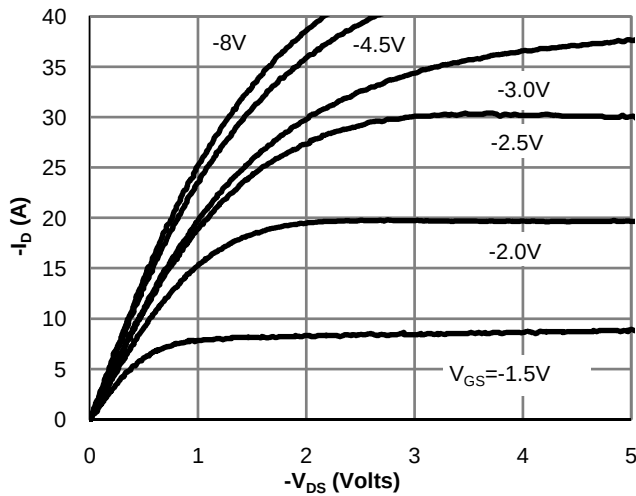


Fig 1: On-Region Characteristics

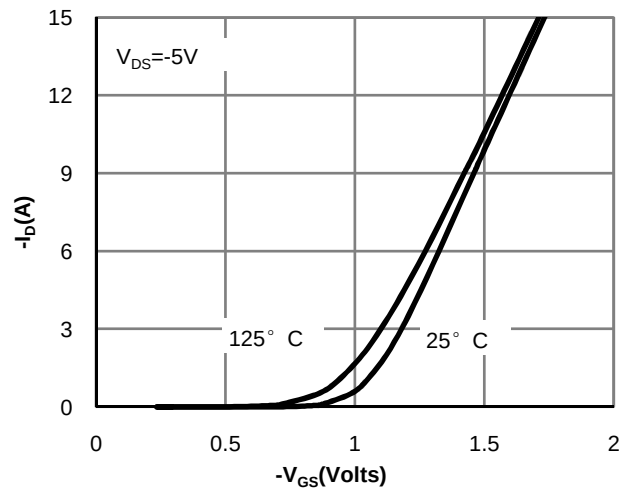


Figure 2: Transfer Characteristics

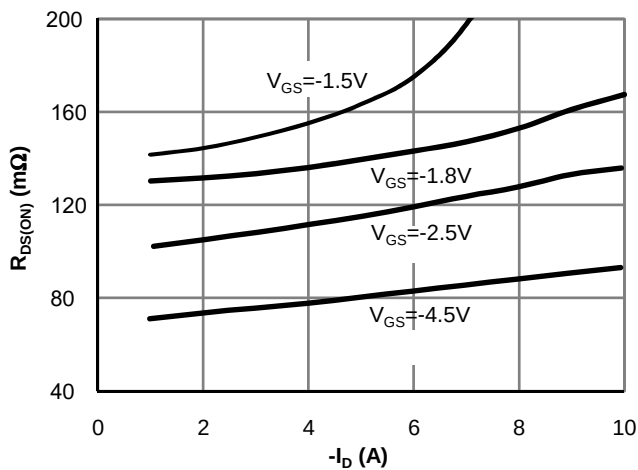


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

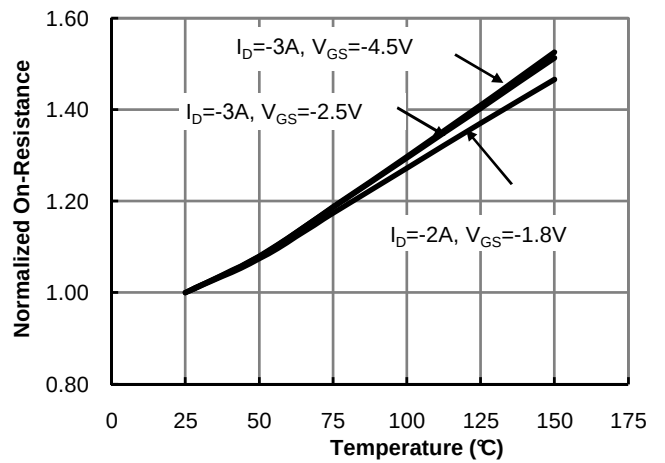


Figure 4: On-Resistance vs. Junction Temperature

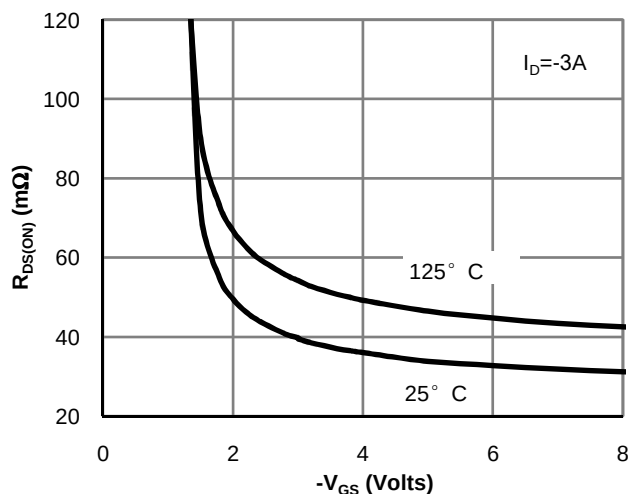


Figure 5: On-Resistance vs. Gate-Source Voltage

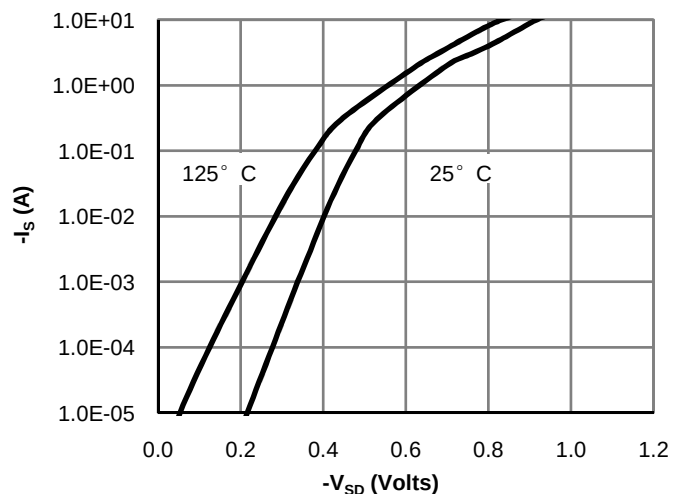
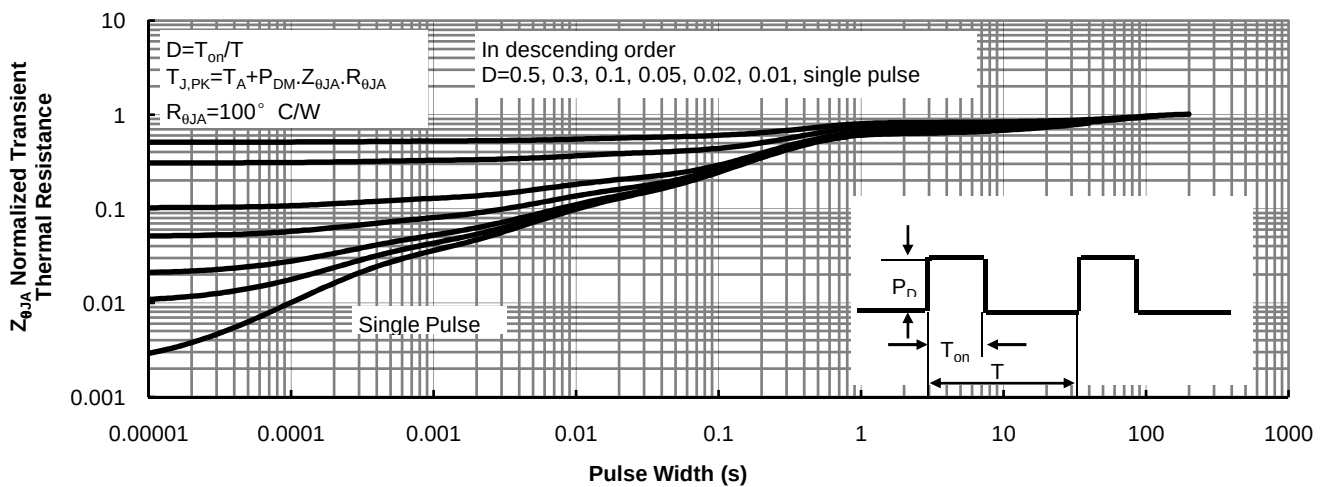
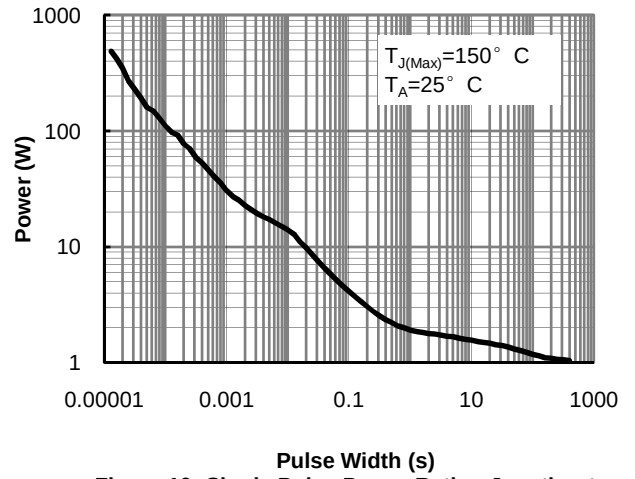
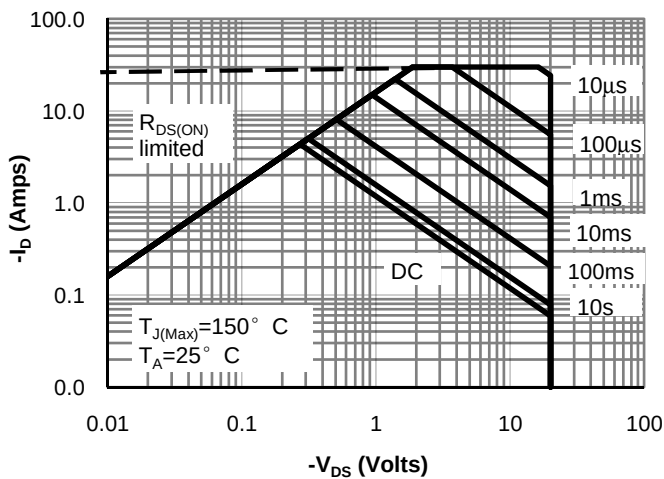
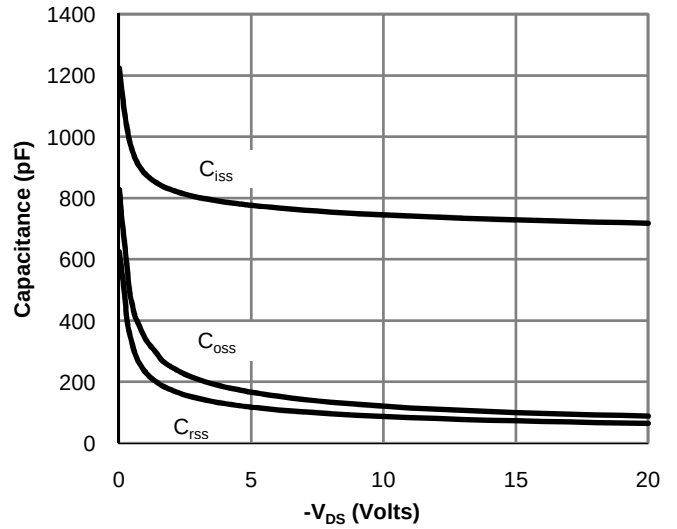
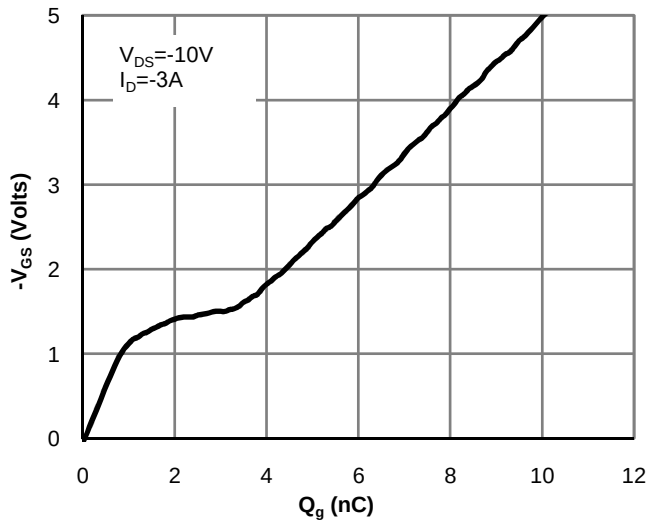


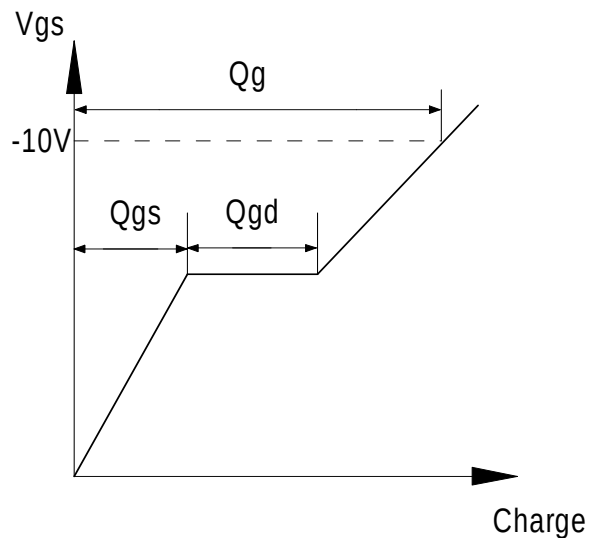
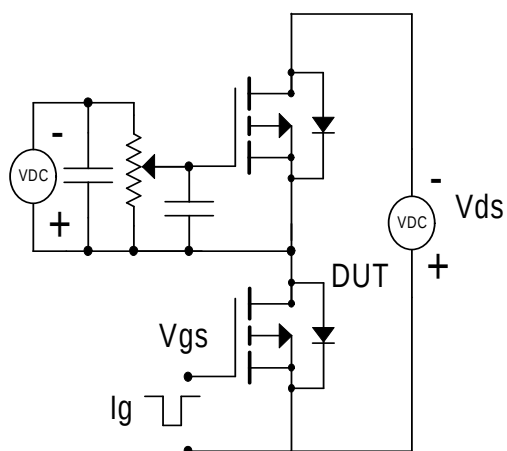
Figure 6: Body-Diode Characteristics

LOW VOLTAGE MOSFET (P-CHANNEL)

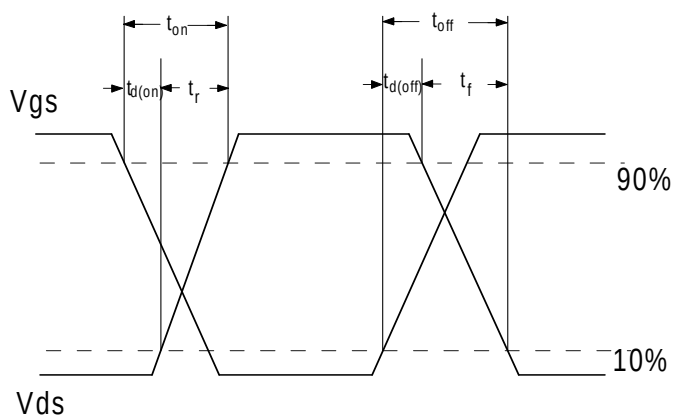
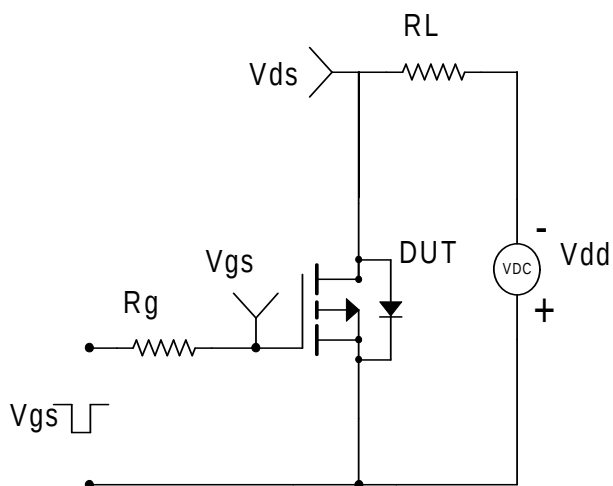


LOW VOLTAGE MOSFET (P-CHANNEL)

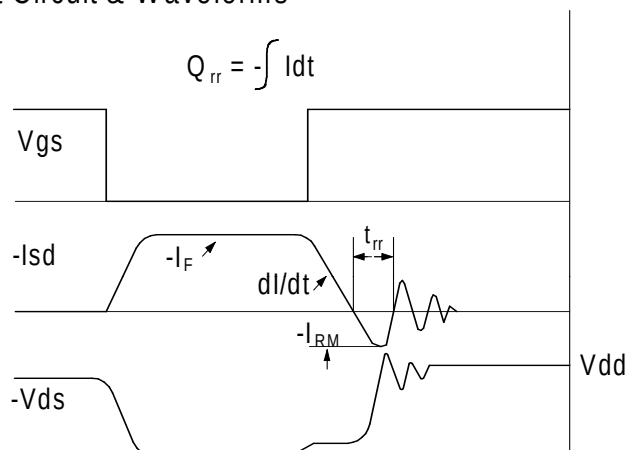
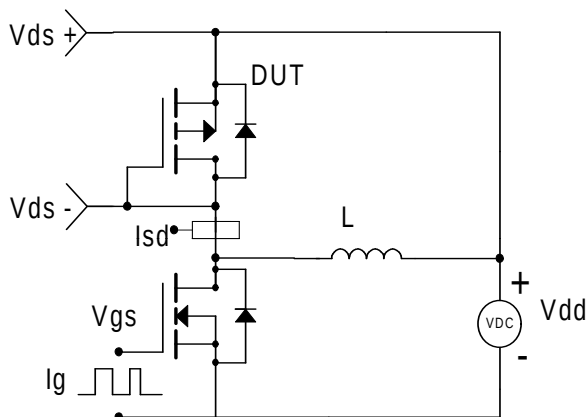
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms

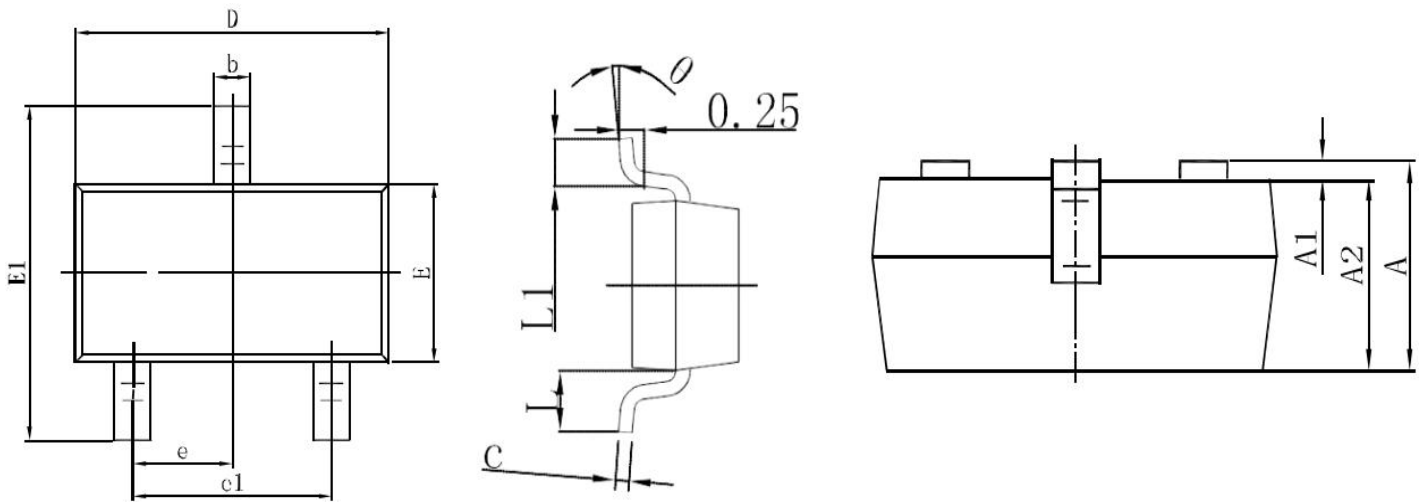


Diode Recovery Test Circuit & Waveforms



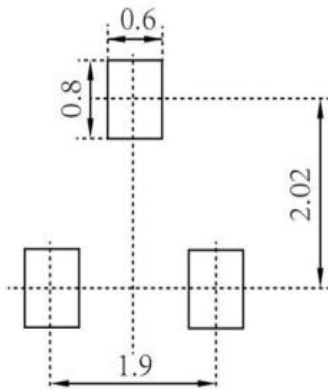
LOW VOLTAGE MOSFET (P-CHANNEL)

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.354	0.453
A1	0.000	0.100	0.000	0.039
A2	0.900	1.050	0.354	0.413
b	0.300	0.500	0.118	0.197
c	0.080	1.150	0.031	0.453
D	2.900	3.100	1.142	1.220
E	1.200	1.400	0.472	0.551
E1	2.250	2.550	0.886	1.004
e	0.95REF		0.374REF	
e1	1.800	2.000	0.709	0.787
L	0.55REF		0.215REF	
L1	0.300	0.500	0.118	0.197

SOT-23 Suggested Pad Layout



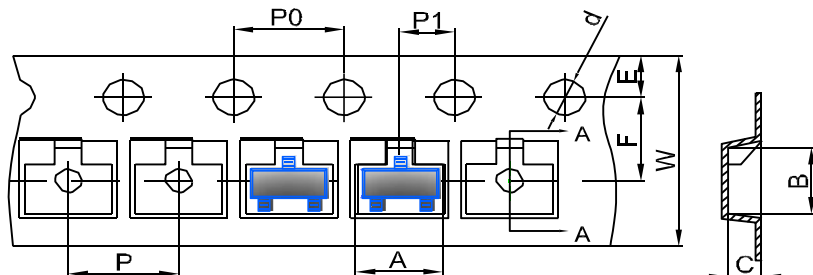
Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

LOW VOLTAGE MOSFET (P-CHANNEL)

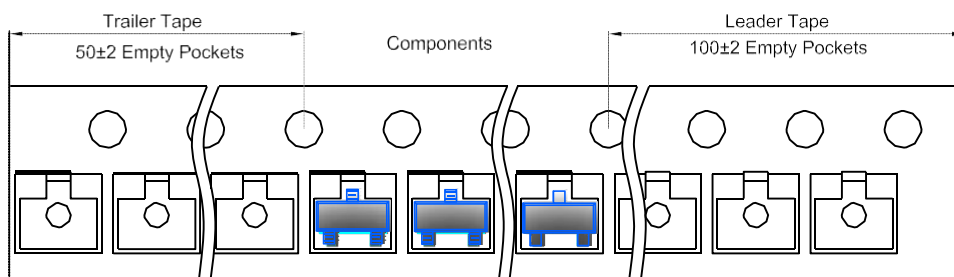
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

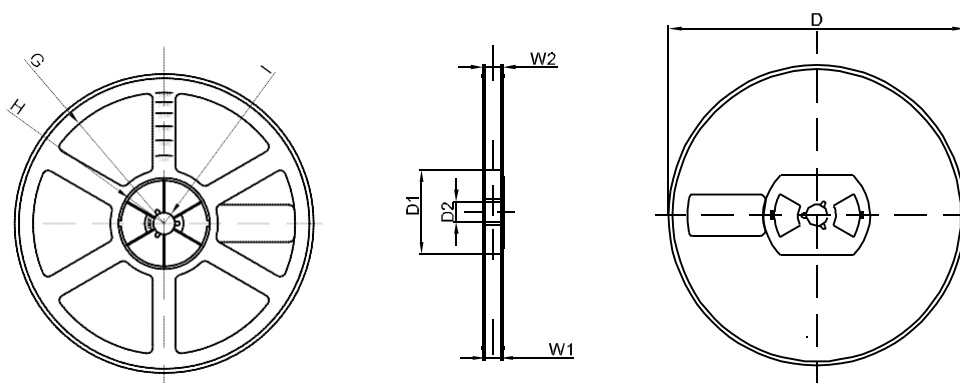


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23 Tape Leader and Trailer



SOT-23 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1